#### IN THE SPECIFICATION:

Please amend the Specification as follows:

Page 1, line 12, change "In the meantime, the" to

--The--;

line 13, delete "in";

line 14, after "substrate" insert

The

substrate is biased -- , change "there are" to -- of -- and delete "some";

line 15, change "advantages," to --advantages

as--;

line 16, after "First," insert -- the biased substrate makes--, delete "is", and after "minimize" insert --a--;

line 17, after "by" insert --a--, delete "it is possible", and after "obtain" insert --an--;

line 19, change "in order to protect" to -- the biased substrate protects -- and after "device" delete ", it is";

line 20, change "possible to suppress" to --by

suppressing -- and after "reducing" insert --a--;

line 21, after "of" insert --a--;

line 22, change second occurrence "the" to --a-- and after "voltage" insert -- (bias) --; and

line 25, change "In the meantime, the" to --A-- and change "of" to --in--.

Page 2, line 4, after "substrate" insert --bias--;
line 5, after "substrate" insert --bias--;
line 10, after "substrate" insert --bias--;
line 13, change "In the meantime, the" to

--The--;

line 14, change "block," to --block of Fig. 1--

;

line 15/ change "being" to --which is-- and delete "apt to be";

line 17, after "substrate" insert --bias--;
line 19 change "being" to --which is-- and

delete "apt to be";

line 22, after "substrate" insert --bias--; line 23, after "in" insert --the--;

line 24, before first occurrence "voltage"

insert --bias--;

line 25, after first occurrence "substrate" insert --bias--, before "small" insert --too-- and after second occurrence "voltage" insert --bias--;

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LEE U.S. APPLICATION -- Appln. No. 08/376,347
                line 27, after "in" insert --the--;
                  line 29, after "substrate" insert --bias-- and
before "large" insert --top-
                  line 30, after "substrate" insert --bias--;
                  line 32, charge "2 receiving" to --2, which
receives --; and
                  line 34, after "substrate" insert --bias-- and
after "VBB" insert --from--.
          Page 3, line 2, after "substrate" insert --bias--;
                  line 3, before "voltage" insert --bias-- and
replace "of" with --from--;
                  line 4, before (first occurrence) "voltage"
insert --bias-- and before (second occurrence) "voltage" insert
--bias--;
                  line 5, before "high" insert --too--;
                  line 7, after "substrate" insert --bias--;
                  line %, before "low," insert --too--;
                  line 10, after "substrate" insert --bias--,
after "VBB" insert -- of the conventional circuit can either --
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and replace "turns" with --turn--;

LEE U.S. APPLICATION -- Appln. No. 08/376,347 line 11, replace "can" with --cannot-- and delete "not"; line 12, replace "14" with --16--; line 13, after "turned-on" and before "," insert -- to at least some extent -- and after "that" insert -- a--; line 15, change "the other" to --another--; line 18, replace first occurrence "the" with -a-- and replace "in" with --when--; line 194 delete "case of powering up of" and after "chip" insert --is powered up--; line 20, delete "specially" and change "the consumption of the" to -- an increased and unnecessary consumption line 21, delete "to be increased"; line 22 change "In the meantime, in" to --In the-- and change "the cell which has the" to --a cell which has

a--;

line 25, charge "In special, a" to --A--; line 28 change "performing low current consumption" to --consumes a low amount of current -- and before "is" insert --as--;

line 20, replace "in" with --on-- and replace ""1993" with --the 1993--;/ line 30, before "well" insert --is--; and line 3%, replace "in" with --during--. Page 4, line 2, change "longer maintained" to --maintained longer--; line 3, after "most" insert --of the--; line 5 / replace third occurrence "the" with -a--; line 7/ change first occurrence "the" with -constant--; line 8 before "case" insert -- the -- and before "time" insert --length of--; line % replace "stayed" with --held--; line 11/ delete/", however, " and after "state" delete ","; line 12,/delete first occurrence "the"; line 14 / after "since" insert -- the length of--; line 17, change "the period of" to --a fixed period designed into--;

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LEE U.S. APPLICATION -- Appln. No., 08/376,347
                  line 18, replace "stayed" with --held--;
                  line 19 /delete "inside of";
                  line 20, before "time" insert --length of-- and
replace "stayed" with --held
                  line 21/delete "in total";
                  line 26, after "having" insert -- an
otherwise--;
                  line 28, after "therefore" insert --an--; and
                  line 32, delete "minimally".
          Page 5, line 1 / after "consumption" insert --to a
minimum--;
                  line 5, after "is" insert --a--;
                  line 6, delete "inside of";
                  line 7, change "generation of" to
--consuming--;
                  line 8, after "still" insert --a--;
                  line 10, delete "inside of" and replace
"generation" with --consuming-
                  line 14, change "of the" to --a--;
                  line 12//after "yet" insert --another--;
                  line 14, replace "an" to --a--;
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LEE U.S. APPLICATION -- Appln. No. 08/376,347
                           change "having as an operational mode"
                  line 15,
to --including--;
                  line 16, replace "the" with --a--;
                  line 18, replace "an" with --a--;
                  line 19, replace "the" with --a--;
                  line 21, change "As the" to --The--;
                  line 22/ charge "synchronizes" to --is
synchronized--;
                  line 23, after mode, insert -- such that--;
and
                  line 24 change ", whereas" to -- and --.
          Page 6, line 8, delete "a";
                  line 14, delete "each of" and after "signals"
insert -- generated by the circuit--;
                  line 16, delete line 16 in its entirety;
                  line 17, replace "a" with --A-- and change "is
to prevent the consumption" to -- according to the present
invention prevents the consumption of -;
           NF -ine 19, replace "generated" with --thereby--;
                  line 20, replace "another" with --the--;
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line 21, before "as" insert --is

defined--, after "except" insert --where otherwise noted such as in--, and delete "determined"; and

line 27/ after "construction" insert --shown in--.

Page 7, line 10, change "in detail explained" to --explained in detail--;

line 11 / change "In the meantime, in" to --In-and before "easily" insert --more--;

line 13 after "As" insert --is-- and after "substrate" insert --bias--;

line 14 replace "carrier" with --carriers--;
line 15 charge "in case that" to --in the case

line 17, before first occurrence "the" insert --during--, delete "there is scarcely", and after "current" insert --is scarcely--;

when--;

line 20, replace "at" with --in-- and delete "of the chip";

line 22, after "substrate" insert --bias--;

line 25, after "substrate" insert --bias--;

line 29, delete "contrary that of";

line 31, change "In the meantime, as mentioned above, if" to --If--;

line 32, replace "stayed" with --held-- and delete "of the chip"; and

line 34, change "operate, however," to --operate.--

Page 8, line 1, before "only" insert --It should--, before "during" insert --operate--, delete ", it should operate", and after "prevent" insert --an increase in the--;

line 2, delete first occurrence "the", after

"consumption" insert --according to the substrate voltage when

in--, delete "under", and delete "of the chip from being";

line 3, delete "increased according to the

substrate voltage";

line 4, change "to be refreshed by the period of the chip," to --occurring every predetermined period, --;

line 5, change "each stayed" to --held--;
line 6, change "period generated in inside of"
to --period as generated within--;

line 7, replace "stayed" with --held--;
line 8, change "Meantime, since" to --Since--;

line 9, replace "decades" with --tens--;
line 26, delete "continuously";
line 27, change "till the substrate" to

--continuously until the substrate bias -- and change "is arrived"

to --arrives--;

line 28, charge "stayed" to --held--; and line 34, after "substrate" insert --bias--.

Page 9, line 2, before "enough" insert --negligible-and delete "small";

line 12, before disclosed" insert --known in the art such as is--;

line 20, change "reversely outputting" to --which inverts--;

line 24, replace "44" with --38-- and replace second occurrence "the" with --a--;

line 26, change "the ground terminal Vss" to -- an NMOS transistor 44--;

line 27 / before "voltage" insert --bias-- and replace "an" with --the--;

line 28, replace "40" with --44-- and change "whose channel is" to --having a channel--;

After line 32, please insert the following paragraph — Those of ordinary skill in the art will appreciate that a NAND gate may be formed by the combination of an AND gate and an inverter, and that a NOR gate may be formed by the combination of an OR gate and an inverter. —; and

line 33, change "4 being the" to --4, which

is an--.

Page 10, line 2, replace "that" with --wherein--;
line 3, before "follows" insert --described

as--;

line //, charge "like an" to --as in--;

line 13, after "substrate" insert

--bias--;

line 14, change In the meantime, in to

--In--;

line 16, after "substrate" insert

--bias--;

line 17 after "level." insert -- In Fig. 4,

waveform (a) shows the signal  $\overline{RAS}$ , waveform (b) shows  $\overline{CAS}$ ,

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waveform (c) shows  $\phi$ , self (d) shows  $\phi$  act, waveform (e) shows the signal at node A shown in Fig. 3, waveform (f) shows the signal at node 24, and waveform (h) shows the substrate bias voltage VBB(-). When signal A is at a low logic level, the substrate voltage level detector 26 is enabled, and when at a logic high level it is disabled. Time T1 is the stand-by state of normal operation mode, time T2 is the stand-by state of the self refresh mode, and Time T3 is the active state of self refresh mode. The time interval  $T_{self-in}$  is the self refresh mode entrance time.

line 20, after "is" insert --described--;

line 26, after "substrate" insert --bias--; line 28, after "42" insert --,--; and line 31, change "NAND gate 34" to --inverter

48--.

Page 11, line 2, change "the detecting operation" to --detecting--;

line 3/ before "voltage" insert --bias-- and

delete "of Fig.";

line 4, delete "4" and after "most" insert

--of the--;

line 17, after "substrate" insert --bias--;

line 21 delete "construction of the";

line 22, change "differently embodied" to

-- constructed differently such as--

line 25, delete/"has";

line 26, change first occurrence "the" to

--includes a--;

line 30, delete "there arises"; and

line 31, after "efficiency" insert --arises--.